

SS12F THRU SS120F

PINNING

PIN

1

2

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 1.0 A

DESCRIPTION

Cathode

Anode

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, fre

ME

• Ca

• Te

• Ap

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

| ee wheeling, and polarity protection applications | |
|--|--|
| ECHANICAL DATA | Top View |
| Case: SMAF | Marking Code: SS12 — SS120 Simplified outline SMAF and symbol |
| Germinals: Solderable per MIL-STD-750, Method 2026 | Simplified duting Sinal and Symbol |
| Approx. Weight: 27mg 0. 00086oz | |
| scalute Maximum Detings and Electrical characteristics | |

| Parameter | Symbols | SS12F | SS14F | SS16F | SS18F | SS110F | SS112F | SS115F | SS120F | Units |
|---|--------------------|------------|-------|-------|-------|----------|--------|--------|---------|-------|
| Maximum Repetitive Peak Reverse Voltage | V _{RRM} | 20 | 40 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum RMS voltage | V _{RMS} | 14 | 28 | 42 | 56 | 70 | 84 | 105 | 140 | ٧ |
| Maximum DC Blocking Voltage | V _{DC} | 20 | 40 | 60 | 80 | 100 | 120 | 150 | 200 | ٧ |
| Maximum Average Forward Rectified Current | I _{F(AV)} | 1.0 | | | | | | | А | |
| Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method) | I _{FSM} | 40 | | | | 30 | | | | А |
| Max Instantaneous Forward Voltage at 1 A | V _F | 0.55 | | 0.70 | | 0.85 | | 0.90 | | V |
| Maximum DC Reverse Current T _a = 25°C at Rated DC Reverse Voltage T _a =100°C | I _R | 0.3 10 | | | | 0.2 5 | | 1276 | .1 2 | mA |
| Typical Junction Capacitance 1) | Cj | 110 | | 80 | | | | | | pF |
| Typical Thermal Resistance 2) | R _{eua} | 115 | | | | | | °C/W | | |
| Operating Junction Temperature Range | Tj | -55 ~ +125 | | | | | | | °C | |
| Storage Temperature Range | T _{stg} | -55 ~ +150 | | | | | | °C | | |

¹⁾ Measured at 1MHz and applied reverse voltage of 4 V D.C.

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²⁾ P.C.B. mounted with 0.2 X 0.2" (5 X 5 mm) copper pad areas.



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Fig.1 Forward Current Derating Curve

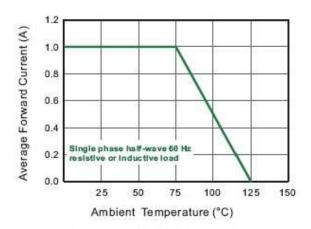


Fig.3 Typical Forward Characteristic

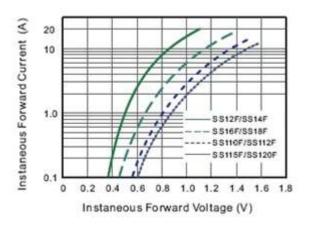


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

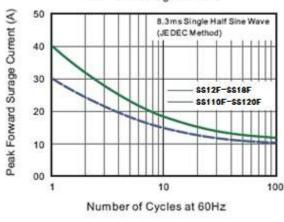


Fig.2 Typical Reverse Characteristics

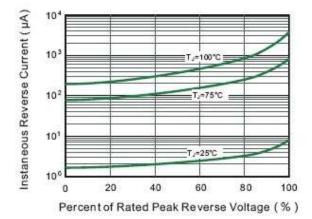


Fig. 4 Typical Junction Capacitance

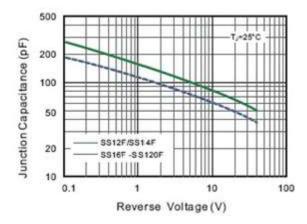
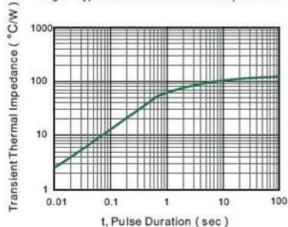


Fig.6- Typical Transient Thermal Impedance



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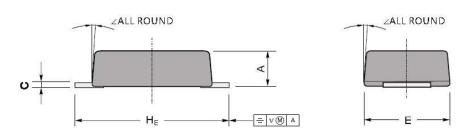


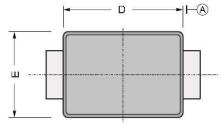
SS12F THRU SS120F

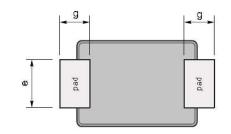
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMAF





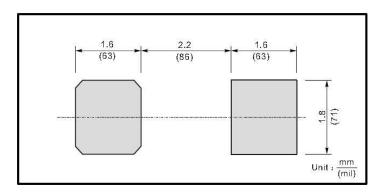


Top View

Bottom View

| UNIT | | Α | O | D | Ш | Ф | 9 | H⊨ | Z |
|------|-----|-----|------|-----|-----|-----|-----|-----|----------|
| mm | max | 1.1 | 0.20 | 3.7 | 2.7 | 1.6 | 1.2 | 4.9 | |
| | min | 0.9 | 0.12 | 3.3 | 2.4 | 1.3 | 8.0 | 4.4 | 7° |
| mil | max | 43 | 7.9 | 146 | 106 | 63 | 47 | 193 | Ţ. |
| | min | 35 | 4.7 | 130 | 94 | 51 | 31 | 173 | |

The recommended mounting pad size



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